TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRANSISTOR

TLP627,TLP627-2,TLP627-4

PROGRAMMABLE CONTROLLERS DC-OUTPUT MODULE TELECOMMUNICATION

The TOSHIBA TLP627,-2 and -4 consists of a gallium arsenide infrared emitting diode optically coupled to a darlington connected phototransistor which has an integral base-emitter resistor to optimize switching speed and elevated temperature characteristics.

The TLP627-2 offers two isolated channels in a eight lead plastic DIP, while the TLP627-4 provide four isolated channels per package.

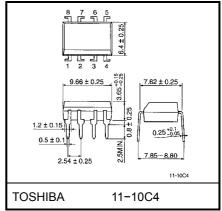
Collector-Emitter Voltage : 300V(Min)
 Current Transfer Ratio : 1000%(Min)
 Isolation Voltage : 5000Vrms(Min)

UL Recognized : UL1577, File No.E67349

	MADE IN JA	PAN	MADE IN THAILAND			
UL Recognized	E67349	*1	E152349	*1		
BSI Approved	7426, 7427	*2	7426, 7427	*2		

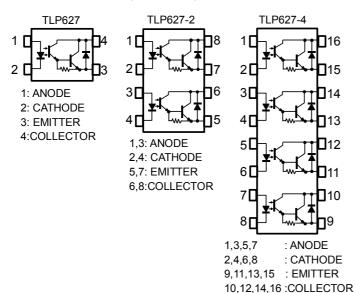
^{*1} UL1577

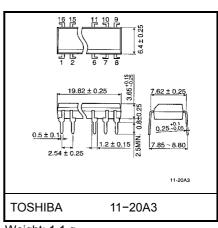
Weight: 0.26 g



Weight: 0.54 g

PIN CONFIGURATION (TOP VIEW)





Weight: 1.1 g

^{*2} BS EN60065 : 1994,BS EN60950: 1992



MAXIMUM RATINGS(Ta=25°C)

	QUADACTERICTIC	0)44501	RATING		LINUT
	CHARACTERISTIC	SYMBOL	TLP627	TLP627-2 TLP627-4	UNIT
	Forward Current	I _F	60	50	mA
	Forward Current Derating	ΔI _F /°C	-0.7(Ta≥39°C)	-0.5(Ta≥25°C)	mA /°C
	Pulse Forward Current	I _{FP}	1(100µs pulse,100pps)		Α
LED	Power Dissipation (1 Circuit)	P _D	100	70	mW
	Power Dissipation Derating (Ta≥25°C,1 Circuit)	Δ P _D /°C	-1.0	-0.7	mW /°C
	Reverse Voltage	V _R	:	5	V
	Junction Temperature	Tj	1:	25	°C
	Collector-Emitter Voltage	V _{CEO}	3	00	V
~	Emitter -Collector Voltage	V _{ECO}	0.3		V
ETECTOR	Collector Current	Ic	1:	50	mA
DETE	Collector Power Dissipation (1 Circuit)	Pc	150(*300)	100	mW
	Collector Power Dissipation Derating (Ta≥25°C,1 Circuit)	Δ P _c /°C	-1.5(*-3.5)	-1.0	mW /°C
	Junction Temperature	Tj	1:	25	°C
Ope	rating Temperature Range	T _{opr}	-55~100		°C
Stor	age Temperature Range	T _{stg}	-55~125		°C
Lead Soldering Temperature (10s)		T _{sold}	260(10sec)		°C
Tota	l Package Power Dissipation	P _T	250(*320)	150	mW
Tota	Total Package Power Dissipation Derating (Ta≥25°C,1 Circuit)		-2.5(*-3.2)	-1.5	mW /°C
Isola	ation Voltage (AC,1min. , R.H.≤60%) (Note1)	BVs	50	000	Vrms

*IF=20mA Max

(Note1)Device considered a two terminal device : LED side pins Shorted together and DETECTOR side pins shorted together.

RECOMMENDED OPERATING CONDITIONS

			ı	1	
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{CC}	-	_	200	V
Forward Current	I _F	_	16	25	mA
Collector Current	Ic	_	_	120	mA
Operating Temperature	T_{opr}	-25	_	85	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta=25°C)

	CHARACTERISTIC SYMBOL TEST CONDITION		MIN.	TYP.	MAX.	UNIT		
	Forward Voltage	V _F	I _F = 10 mA		1.15	1.3	V	
LED	Reverse Current	I _R	V _R = 5 V		_	10	μΑ	
	Capacitance	Ст	V = 0 , f=1MHz	_	30	_	pF	
	Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	IC = 0.1mA	300	_	ı	V	
CTOR	Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	IE = 0.1mA	0.3		1	V	
TEC	Collector Dark Current		collector Dark Current	V _{CE} = 200V	_	10	200	nA
DE			V _{CE} = 200V , Ta = 85°C	_	_	20	μA	
	Capacitance Collector to Emitter	C _{CE}	V=0 , f=1MHz		10		pF	

COUPLED ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	I_{C}/I_{F}	I _F =1mA , V _{CE} =1V	1000	4000	_	%
Saturated CTR	I _C /I _F (sat)	I _F =10mA , V _{CE} =1V	500	_	_	%
Collector-Emitter	\/(eat)	I _C =10mA , I _F =1mA	_	_	1.0	V
Saturation Voltage	V _{CE} (sat)	I _C =100mA , I _F =10mA	0.3	_	1.2	, v

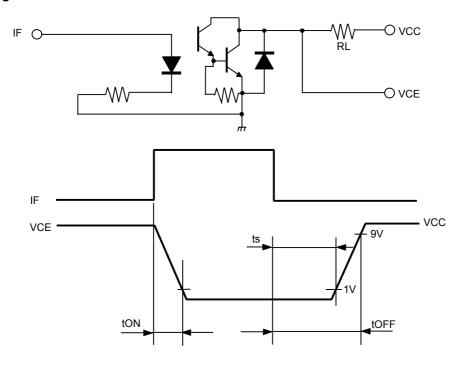
ISOLATION ELECTRICAL CHARACTERISTICS (Ta=25°C)

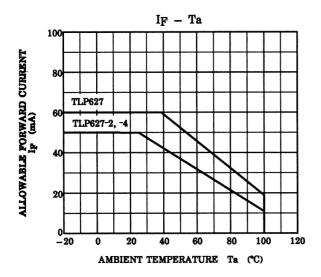
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	Cs	V _S =0 , f=1MHz	_	8.0	_	pF
Isolation Resistance	Rs	V _S =500V , R.H.≤60%	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation Voltage	BVs	AC, 1minute	5000	_	_	Vrms
		AC, 1second, in oil	_	10000	_	VIIIIS
		DC, 1 minute, in oil	-	10000	-	Vdc

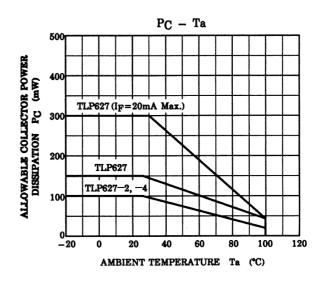
SWITCHING CHARACTERISTICS (Ta=25°C)

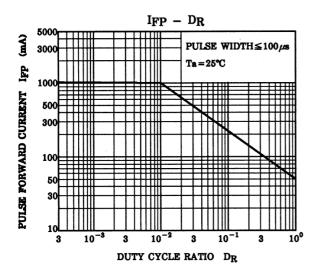
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Rise Time	tr		_	40	_	
Fall Time	tf	V _{cc} =10V I _c =10mA	_	15	_	
Turn-on Time	ton	$R_L=100\Omega$	_	50	_	
Turn-off Time	toff		_	15	_	μs
Turn-on Time	tON	R _L =180Ω (Fig.1) V _{CC} =10V , I _F =16mA	_	5	_	
Strage Time	ts		_	40	_	
Turn-off Time	tOFF		_	80	_	

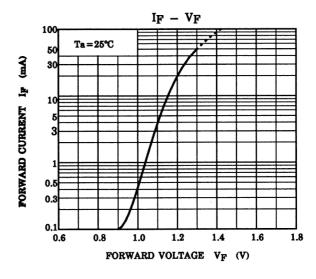
Fig.1 SWITCHING TIME TEST CIRCUIT

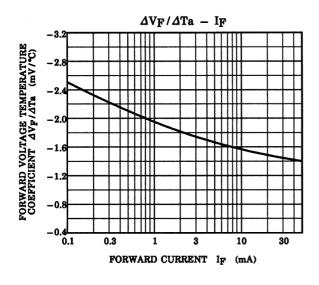


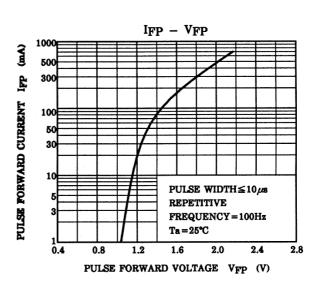


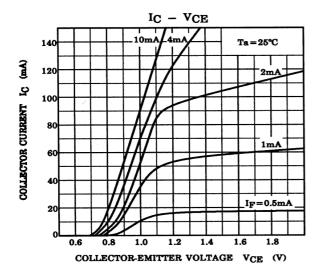


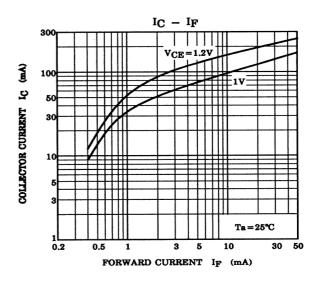


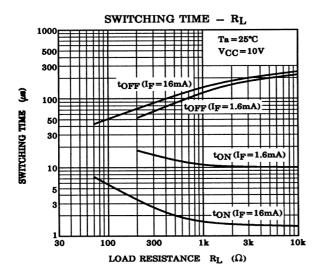


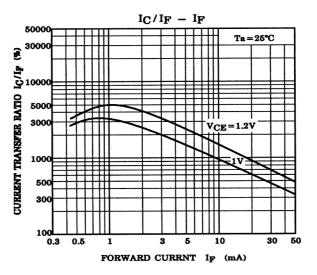


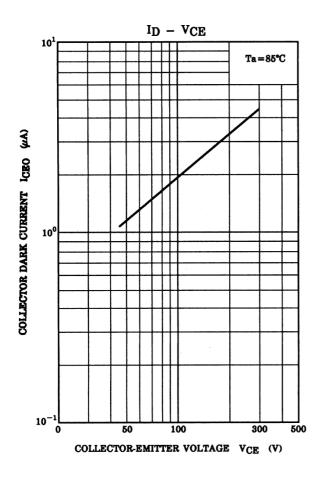


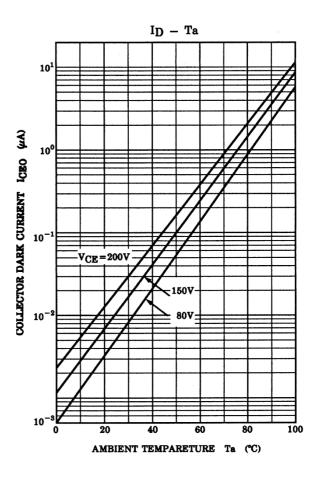


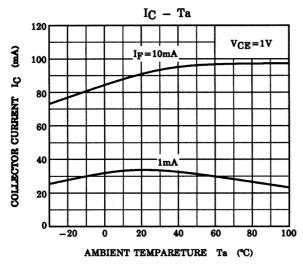


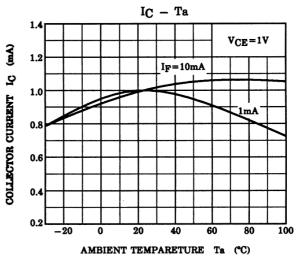












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2002-06-24

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